


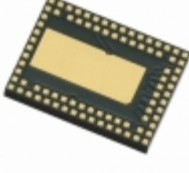





	<h2>SI1022R-T1-E3</h2>
	<p>Hersteller-Teilenummer: SI1022R-T1-E3</p> <p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p> <p>Teil der Beschreibung: MOSFET N-CH 60V 330MA SC-75A</p> <p>Datenblätter:  SI1022R-T1-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 71295 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI1022R-T1-E3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET N-CH 60V 330MA SC-75A
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	71295 pcs Stock
detaillierte Beschreibung	N-Channel 60V 330mA (Ta) 250mW (Ta) Surface
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	SC-75A
Supplier Device-Gehäuse	SC-75A
Verlustleistung (max)	250mW (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	330mA (Ta)
Rds On (Max) @ Id, Vgs	1.25 Ohm @ 500mA, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	0.6nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	30pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SI1022R-T1-E3TR

SI1022R-T1-E3 ist neu im Original, Suche SI1022R-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI1022R-T1-E3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI1022R-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 SI1022R-T1 VISHAY SI1022R-T1 VISHAY	 SI1022R VISHAY SI1022R VISHAY	 SI1022-B-GM3R Energy Micro (Silicon Labs) IC RF TXRX+MCU ISM<1GHZ 85-VFLGA	 SI1022R-T1-GE3 Vishay / Siliconix MOSFET N-CH 60V 330MA SC-75A
 SI1022R-T1-E3 VISHAY SI1022R-T1-E3 VISHAY	 SI1023-A-GM Energy Micro (Silicon Labs) IC RF TXRX+MCU ISM<1GHZ 85-VFLGA	 SI1022R-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 60V 330MA SC-75A	 SI1022R-T1-E3 Vishay / Siliconix MOSFET N-CH 60V 330MA SC-75A

heiße Teile

Mehr

SI1012X-T1-GE3	SI1013CX-T1-GE3	SI1013CX-T1-GE3	SI1013R-T1	SI1013R-T1-E3
SI1013R-T1-E3	SI1013R-T1-GE3	SI1013R-T1-GE3	SI1013X-T1	SI1013X-T1-E3
SI1013X-T1-E3	SI1013X-T1-GE3	SI1013X-T1-GE3	SI1016CX-T1-GE3	SI1016CX-T1-GE3
SI1016X-T1-E3	SI1016X-T1-E3	SI1016X-T1-GE3	SI1016X-T1-GE3	SI1016X2-T1-GE3
SI1021R-T1	SI1021R-T1-E3	SI1021R-T1-E3	SI1022R-T1	SI1022R-T1-E3
SI1022R-T1-GE3	SI1022R-T1-GE3	SI1022R-T1-E3	SI1023CX-T1-GE3	SI1023CX-T1-GE3
SI1023X-T1	SI1023X-T1-E3	SI1023X-T1-E3	SI1023X-T1-GE3	SI1023X-T1-GE3
SI1024-T1	SI1024X-T1	SI1024X-T1-E3	SI1024X-T1-E3	SI1024X-T1-GE3
SI1024X-T1-GE3	SI1024X-T1-GE3	SI1025X-T1	SI1025X-T1-E3	SI1025X-T1-E3
SI1026X-T1	SI1026X-T1-E3	SI1026X-T1-E3	SI1026X-T1-GE3	SI1026X-T1-GE3

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